NSN 5961-01-156-7901



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-156-7901 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.300 inches **Overall Width:** 1.050 inches **End Application:** 5895-01-129-1827 **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 collector to emitter voltage/static/base open and 500.0 collector to emitter voltage, dc with specified circuit between base and emitter and 8.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** 20.00 amperes source cutoff current and 2.50 amperes source cutoff current **Power Rating Per Characteristic:** 175.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 uninsulated wire lead Shelf Life:

No

N/a

Unit Of Measure:

Demilitarization:

NSN 5961-01-156-7901 Transistor - Page 2 of 2



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